



Dispositivos baseados em nanomembranas híbridas: um caso onde o micro e o nano se complementam através da auto-organização

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Research scope



Nanomembranes: Third wave of works on nanomaterials

Nanomembranes are structures with <u>thicknesses of less than a few hundred nanometers</u> and with minimum <u>lateral dimensions at least two orders of magnitude larger than the</u> <u>thickness.</u>



Applications of nanomembranes

- ultra-compact functional devices;
- μ-containers and μ-fluidic elements;
- 3D electronics.

NANOLETTERS

Self-Assembled Ultra-Compact Energy Storage Elements Based on Hybrid Nanomembranes



NANO LETTERS



Rolled-up nanomembranes as compact 3D architectures for field effect transistors and fluidic sensing applications

Rolled-up nanomembrane transistor for microfluidics





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Hybrid organic – inorganic heterojunctions based on nanomembranes

- Molecular heterojunctions;
- Hybrid sensors;
- 3D ultra-compact organic devices;



Polypyrrole thin-film field-effect transistor



Contents lists available at ScienceDirect

Sensors and Actuators A: Physical

Piezoresistance in chemically synthesized polypyrrole thin films



NANO LETTERS

Hybrid Organic/Inorganic Molecular Heterojunctions Based on Strained Nanomembranes



PHYSICAL REVIEW B 76, 245206 (2007)

Transport properties of chemically synthesized polypyrrole thin films



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IFSC-USP, November 2013

I FTTER

pubs.acs.org/NanoLett

Self-releasing in everyday life

The Tension of Metallic Films deposited by Electrolysis. By G. GERALD STONEY.

(Communicated by the Hon. C. A. Parsons, C.B., V.-P.R.S. Received January 16, —Read February 4, 1909.)

It is well known that metallic films deposited electrolytically are in many cases liable to peel off if deposited to any considerable thickness. This is the case with nickel which, when deposited over a certain thickness, will curl up into beautiful close rolls, especially if it does not adhere very tightly to the body on which it is deposited. For example, if a piece of glass is



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Basics on strained nanomembranes

From nano to micro: the art of shaping nanomembranes (a research field by itself)

Substrate: glass, Si/SiO₂, Si, GaAs ...

Sacrificial layer: photoresist, GeO₂, AlAs, Ge ...

Strained layer: metals, oxides and semiconductors



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Selective removal of the sacrificial layer:

- $H_2O + H_2O_2$ (0% to 3%)
- H₂O + HF (0.5% to 2%)
- Acetone

Spring loaded. When a film is freed, its top layer contracts, and its bottom layer expands, causing the film to curl and roll.

A. Cho, Science **313**, 164 (2006)





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Patterning of regular arrays

Strained bilayer: Ti/Cr (15/20nm)Sacrificial layer: GeO₂ (~20nm) Substrate: Si/SiO₂



 $\Phi = 1\mu m \cdot 100\mu m$

Schadewald and Bof Bufon; IIN Chemnitz, 2010

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Rolling in H₂O

Hybrid Organic/Inorganic Heterojunctions

Molecular (hetero)-junctions



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Technological challenges



Contacting molecular layers: challenges



Hybrid junctions based on nanomembranes



- Pinhole-proof;
- Soft contact: low damage to the MoLa;
- "Large scale" production and integration;
- Versatile material composition;
- Self-adjusting gap.

Soft mechanical contacting method: Self-adjusting contacts.



Haick et al., Acc. Chem. Res. 41, 359 (2008)





Combination of metal and semiconductor contacts



Contacting CuPc thin films (Au/CuPc/Au)





Submittend to JPC-C

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Transport properties of CuPc thin films: IV and IT traces



- For V < 0.15V and T > 100 140 K, hopping conduction dominates;
- At $T = T_1$: transition from thermally activated transport to tunneling;
- Strong temperature dependence for T > T₁ associated to impurity/defect (ID) sites;
 For T > T₁:

$$I \propto V \exp\left(-\frac{E_a}{kT}\right)$$

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Au/CuPc/Au

- Rolled-up nanomembranes can gently contact ultra-thin organic semiconducting layers from the top;
- No interdiffusion of metallic atoms was detected.





Submittend to JPC-C

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Au/SAM/Au heterojunctions



C.C.Bof Bufon et al., Nano Lett. 11, 3727 (2011)

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Question of perspective

Tube Ø ~ 5-10μm

Chain Length (C6-C18 thiol) ~ 0.7-2.3nm



Combination of metal and semiconductor contacts

Nanomembrane based top <u>metallic</u> contact



Semiconductor/SAM/semiconductor heterojunctions

Contacting molecules on semiconducting fingers with semiconducting tubes

Concept of radial injection and tangential



Semiconductor

Semiconductor

SAM

pGaAs-C16PA/nInGaAs



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C.C.Bof Bufon *et al.*, *Nano Lett.* 11, 3727 (2011)

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C.C.Bof Bufon *et al.*, *Nano Lett.* 11, 3727 (2011)

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Curly contacts

Christian Martin

Nature Materials 10, 724 (2011) doi:10.1038/nmat3135 Published online 23 September 2011

Applying reliable electrical contacts to self-assembled molecular monolayers poses a persistent challenge in molecular electronics. Evaporated metal top electrodes can cause short circuits at monolayer defects, and solution-processed conducting polymer electrodes may show temperature-dependent electrical characteristics that disguise the physics of molecular charge transport. Carlos Cesar Bof Bufon and colleagues have now developed a process that allows them to contact molecular monolayers using predefined metal and inorganic semiconductor lay...



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"The interesting fundamental science, the diverse possibilities for creative engineering and the strong potential for broadly influential outcomes make this field of nanomembranes research a fertile one for future investigation."

> J. A. Rogers, M. G. Lagally & R. G. Nuzzo Nature 477, 45, 2011

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